2SA1531, 2SA1531A

Silicon PNP epitaxial planer type

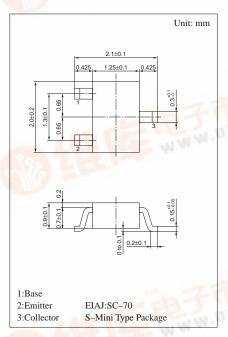
For low-frequency and low-noise amplification Complementary to 2SC3929 and 2SC3929A

Features

- Low noise voltage NV.
- High foward current transfer ratio h_{FE}.
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit	
Collector to	2SA1531	V	-35	V	
base voltage	2SA1531A	V_{CBO}	-55	CC.COP	
Collector to	2SA1531	V	-35	V	
emitter voltage	2SA1531A	V _{CEO}	-55	V	
Emitter to base voltage		$V_{\rm EBO}$	-5	V	
Peak collector current		I_{CP}	-100	mA	
Collector current		I_C	-50	mA	
Collector power dissipation		P_{C}	150	mW	
Junction temperature		T_{j}	150	°C	
Storage temperature		T_{stg}	−55 ~ +150	°C	



Marking symbol : F(2SA1531) H(2SA1531A)

Electrical Characteristics (Ta=25°C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current		I_{CBO}	$V_{CB} = -10V, I_E = 0$			-100	nA
		I _{CEO}	$V_{CE} = -10V, I_B = 0$			-1	μΑ
Collector to base	2SA1531	N/	I 100A I 0	-35			v
voltage	2SA1531A	V _{CBO}	$I_{\rm C} = -10\mu A, I_{\rm E} = 0$	-55			
Collector to emitter	2SA1531			-35			v
voltage	2SA1531A	V _{CEO}	$I_C = -2mA, I_B = 0$	-55		- W	
Emitter to base voltage		V _{EBO}	$I_{\rm E} = -10\mu A, I_{\rm C} = 0$	-5			V
Forward current transfer ratio		h _{FE} *1	$V_{CE} = -5V, I_{C} = -2mA$	180		700	
Collector to emitter saturation voltage		V _{CE(sat)}	$I_C = -100 \text{mA}, I_B = -10 \text{mA}^{*2}$			- 0.6	V
Base to emitter voltage		V _{BE}	$V_{CE} = -1V, I_{C} = -100 \text{mA}^{*2}$		- 0.7	-1.0	V
Transition frequency f		f_{T}	$V_{CB} = -10V$, $I_E = 2mA$, $f = 200MHz$		80		MHz
Noise voltage		NV	$V_{CE} = -10V$, $I_{C} = -1mA$, $G_{V} = 80dB$ $R_{g} = 100k\Omega$, Function = FLAT			150	mV

^{*1}hFE1 Rank classification

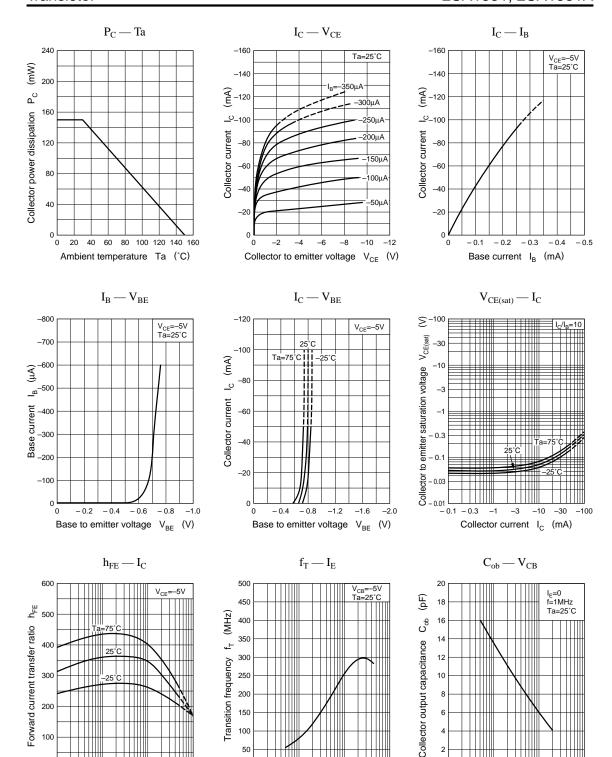
Rank		R	S	Т	
找電船		180 ~ 360	260 ~ 520	360 ~ 700	
Marking	2SA1531	FR	FS	FT	
Cosymbosc.co	28A1531A	HR	HS	HT	

^{*2} Pulse measurement

0 - 0.1 - 0.1 - 0.3

-3

Collector to base voltage $\ V_{CB} \ (V)$

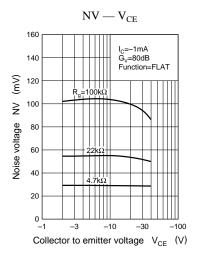


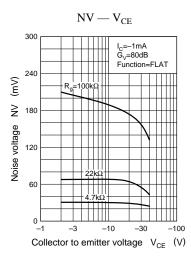
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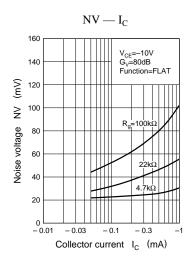
Collector current I_C (mA)

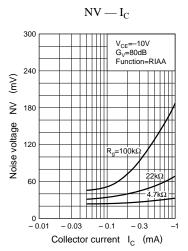
0.3

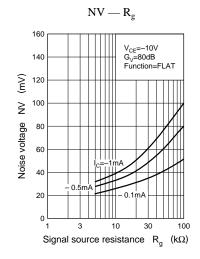
Emitter current I_E (mA)

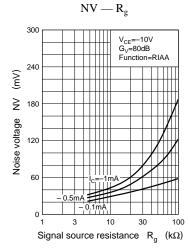












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